

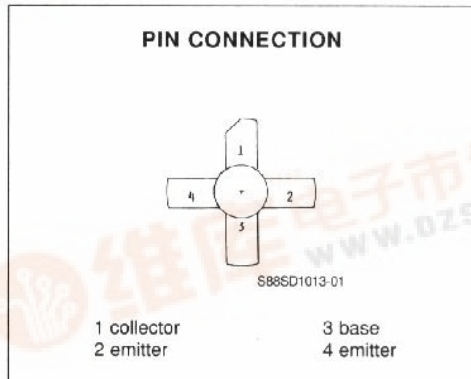
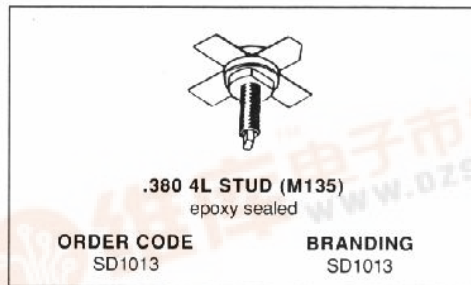


140 Commerce Drive
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Tel: (215) 631-9840

SD1013

**RF & MICROWAVE TRANSISTORS
108-152MHz APPLICATIONS**

- FM CLASS C TRANSISTOR
- FREQUENCY 150MHz
- VOLTAGE 28V
- POWER OUT 10W
- POWER GAIN 10dB
- EFFICIENCY 55% TYP
- COMMON EMITTER



DESCRIPTION

The SD1013 is a 28V epitaxial silicon NPN planar transistor designed for 108-152 MHz FM applications. This device utilizes diffused emitter resistors to achieve infinite VSWR at rated operating conditions.

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector - Base Voltage	65.0	V
V _{CEO}	Collector - Emitter Voltage	35.0	V
V _{CES}	Collector - Emitter Voltage	65.0	V
V _{EBO}	Emitter - Base Voltage	4.0	V
I _C	Collector Current	1.0	A
P _{tot}	Total Power Dissipation	13.0	W
T _{stg}	Storage Temperature	- 65 to 150	°C
T _j	Junction Temperature	200	°C

THERMAL DATA

R _{th(j-c)}	Junction-case Thermal Resistance	13.5	°C/W
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March 1989

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ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}C$)

STATIC

Symbol	Test Conditions		Value			Unit
			Min.	Typ.	Max.	
BV_{CBO}	$I_C = 20mA$	$I_E = 0$	65.0			V
BV_{CES}	$I_C = 200mA$	$V_{BE} = 0$	65.0			V
BV_{CEO}	$I_C = 200mA$	$I_B = 0$	35.0			V
BV_{EBO}	$I_E = 10.0mA$	$I_C = 0$	4.0			V
I_{CBO}	$V_{CB} = 30.0V$	$I_E = 0$			1.0	mA
h_{FE}	$V_{CE} = 5.0V$	$I_C = 200mA$	5.0			

DYNAMIC

Symbol	Test Conditions			Value			Unit
				Min.	Typ.	Max.	
P_O	$f = 150MHz$	$V_{CC} = 28.0V$				10.0	W
G_P	$f = 150MHz$	$V_{CC} = 28.0V$				10.0	dB
C_{ob}	$f = 1MHz$	$V_{CB} = 30.0V$	$I_E = 0$			15	pF

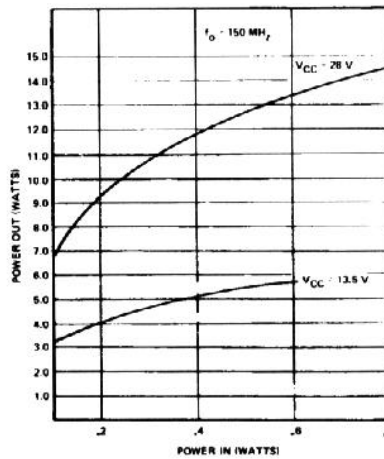
When used at 13.5Volts performances are :

$P_{out} = 3.5Watt$ typical.

$G_p = 10.5dB$ typical.

APPLICATION INFORMATION (typical curves)

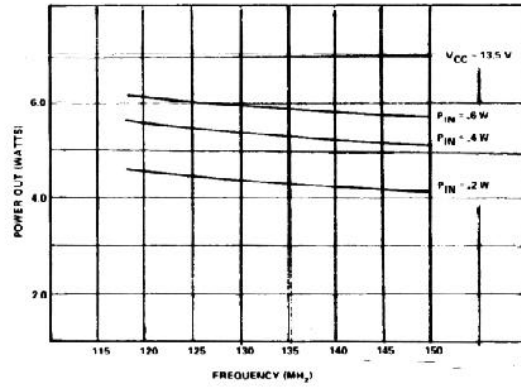
POWER OUT VS POWER IN



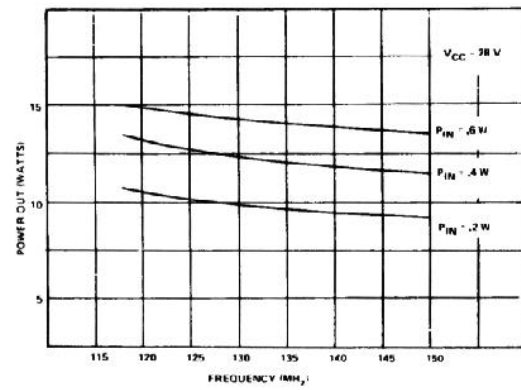
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APPLICATION INFORMATION (typical curves)

POWER OUT VS FREQUENCY (13.5V, 28V)



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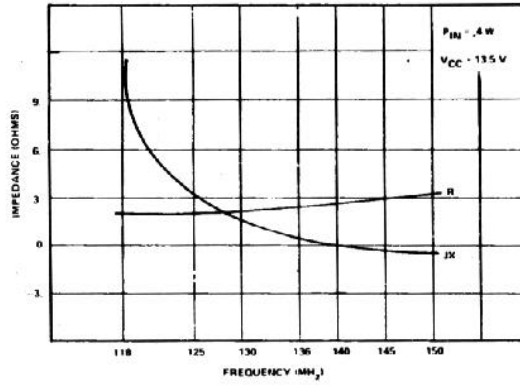


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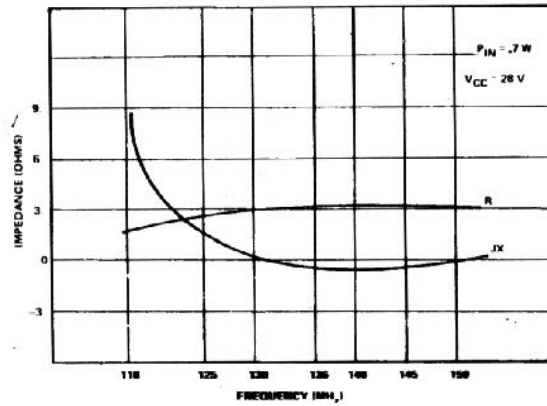
SD1013

IMPEDANCES DATAS (typical)

SERIES SOURCE IMPEDANCE VS FREQUENCY (13.5V, 28V)



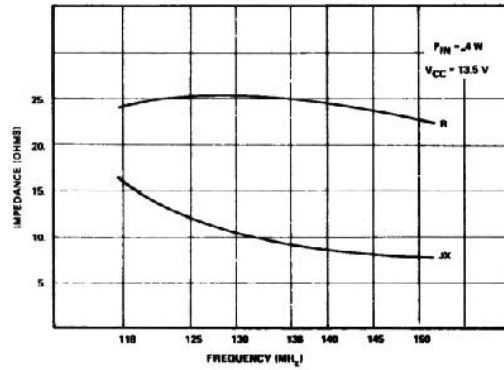
S88-SD1013-05



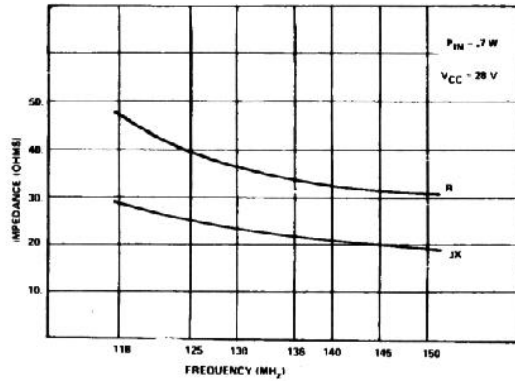
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IMPEDANCES DATAS (typical)(continued)

SERIES COLLECTOR LOAD IMPEDANCE VS FREQUENCY (13.5V, 28V)

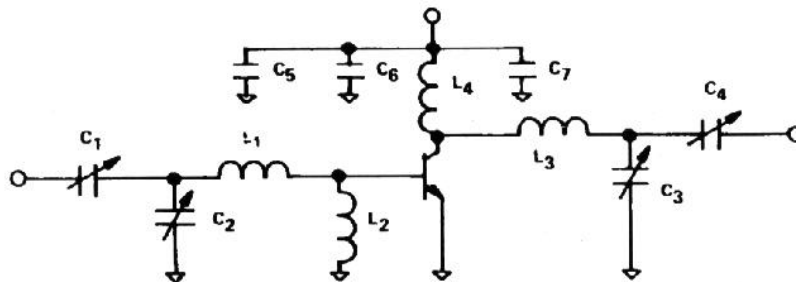
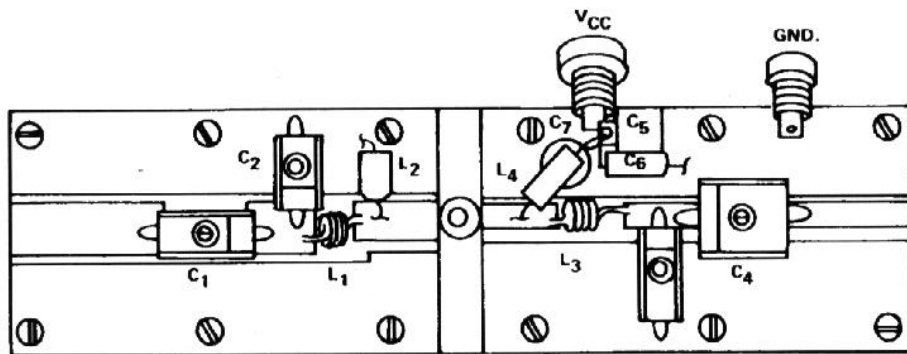


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S88-SD1013-08

TEST FIXTURE

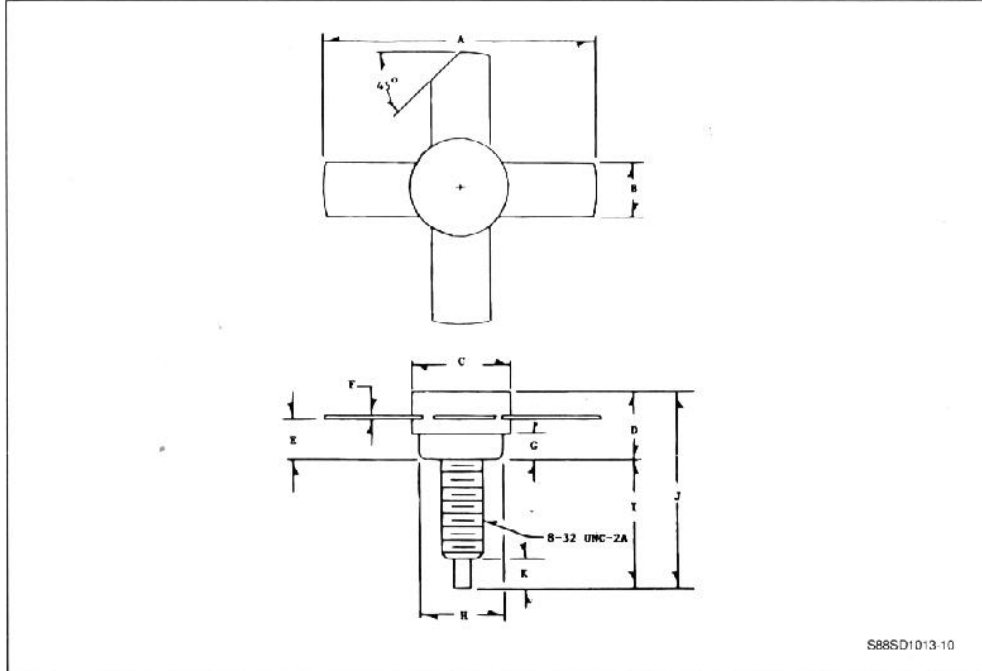


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|---------------------------------|------------------------|----------------|--------------------|
| C ₁ , C ₂ | ARCO 422 | C ₇ | .01pf CERAMIC DISC |
| C ₃ | ARCO 421 | L ₁ | 3T #22, 1/8 ID |
| C ₄ | ARCO 464 | L ₂ | RFC FERROXCUBE |
| C ₅ | 1000pf UNELCO | L ₃ | 3T #18, 1/4 ID |
| C ₆ | 10μf, ELECTROLYTIC 35V | L ₄ | .47μh MOLDED CHOKE |

PACKAGE MECHANICAL DATA

.380 4L STUD



	Minimum Inches	Maximum Inches
A	.980	
B	.220	.230
C	.370	.385
D		.275
E	.155	.175
F	.004	.007

	Minimum Inches	Maximum Inches
G	.090	.100
H	.320	.330
I	.450	.490
J		.750
K	.100	.130